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Innovative Silicon Secures \$25M in Series C Funding

Wellington Partners leads financing round and joins Austin Ventures, Auriga Partners, Highland Capital Partners, Index Ventures, and Soitec in backing the developer of ultra-dense Z-RAM memory technology

SANTA CLARA, Calif.,— November 5, 2007 — Innovative Silicon Inc. (ISi), the developer of Z-RAM® ultra-dense memory intellectual property (IP), announced today that Wellington Partners Venture Capital has joined with all existing investors to lead a \$25M Series C round of investment in the company. ISi will use the financing to expand its engineering and customer support initiatives worldwide.

ISi's Z-RAM is the world's lowest cost memory solution, offering higher density than today's DRAM and SRAM technologies, and the manufacturing simplicity of a single-transistor cell. AMD and Hynix Semiconductor have recently licensed Z-RAM memory technology for future microprocessor and stand-alone DRAM products.

Wellington Partners is an active and focused investor in semiconductor technologies, with a particular interest in process and manufacturing technologies that create opportunities to change large markets. "Recent multi-million dollar deals with leading DRAM maker, Hynix, and

microprocessor giant AMD, clearly position ISi's Z-RAM as the leader for both stand-alone and embedded next-generation memories," said Bart Markus, general partner at Wellington Partners. "We are delighted to be a part of this next, exciting phase in the development of Innovative Silicon Inc."

"Wellington Partners adds another prestigious firm to our existing investors and provides further endorsement of the strength of our business and technology vision going forward," said Mark-Eric Jones, ISi President and CEO. "This round of financing will not only fuel the rapid growth ISi is experiencing now, but will also provide additional financial stability as ISi attracts top industry talent in support of our customer and product initiatives."

About Innovative Silicon

Innovative Silicon Inc. (ISi) delivers ultra-high density memory IP for embedded SoC, MPU and portable consumer applications requiring low power, high density and high speed. Endorsed by IEEE Spectrum Magazine in January 2007 as the winning semiconductor technology, and again in April 2007 by winning its ACE award for Emerging Technology, ISi's Z-RAM® memory offers up to twice the density of embedded DRAM and is up to five times denser than embedded SRAM. Z-RAM memory is currently being licensed by Hynix Semiconductor for use in its DRAM chips. The company closed its first round of VC funding in 2003, completed its first 90nm megabit Z-RAM memory designs in 2004, its first 65nm designs in 2005 and its first 45nm designs in 2006. With more than 20 patents already granted, Z-RAM's unique single-transistor architecture is the world's lowest cost semiconductor memory solution. The company is incorporated in the USA with R&D in Lausanne, Switzerland. For more information see www.z-ram.com.

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